Component & Device Parameter Test Instruments

I. TH510 Series Semiconductor C-V Characteristic Analyzer

Features

■ integrated design:

LCR+gate voltage $V_{\rm DS}$ +drain voltage $V_{\rm DS}$ +channel switching+host computer software

- Gate voltage V_{GS}: 0 ±40V
- Drain voltage V_{DS}: 0 ±200V/±1500V/±3000V
- Single tube device (spot test), module device (list scan), curve scan (optional)
 Three testing methods
- Four parasitic parameters (Ciss,Coss,Crss,Rg or Cies,Coes,Cres,Rg)
 One-click measurement and display on the same screen
- Standard 2 channels, expandable to 6 channels, capable of testing single tube, multi-core or module devices (TH511E/TH513 only has 1 channel)
- CV curve scan, Ciss-Rg curve scan
- Capacitor fast charging technology enables fast testing
- Contact Check Cont
- Continuity test OP_SH
- Automatic delay setting
- Crss Plus function: solve the problem of negative Crss value at high frequency
- High-voltage breakdown protection: DS instantaneous short circuit to protect the instrument
- Interlock safety lock function: add high-voltage protective wall (TH513 only)
- Cs-V function: test and analysis of diode junction capacitance CV characteristics
- Equivalent mode conversion function, optional Cs or Cp mode
- 10 levels of sorting

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TH510 Series

Dimension: 430(W)x177(H)x265(D)

Weight: about 16kg

Applications

■ Semiconductor components/Power components

Parasitic capacitance test and C-V characteristic analysis of diodes, triodes, MOSFETs, IGBTs, thyristors, integrated circuits, optoelectronic chips, etc.

Semiconductor material

Wafer dicing, C-V characteristic analysis

■ Liquid crystal material

Elastic constant analysis

Specifications

Model		TH511		TH512	TH513		
Channel		2 (4/6 Ch Optional)	2 (4/6 Ch Optional)				
Display	Display	10.1-inch capacitive tou	10.1-inch capacitive touchscreen				
	Ratio	16:9	16:9				
	Resolution	1280×RGB×800	1280×RGB×800				
Test Parameter		$C_{ISS}, C_{OSS}, C_{RSS}, R_g$. Four parameter selectable arbitrarily					
Test Frequency	Range	10kHz-2MHz	10kHz-2MHz				
	Accuracy	0.01%	0.01%				
		10mHz	1.0000	1.00000kHz-9.99999kHz			
	Resolution	100mHz	10.000	10.0000kHz-99.9999kHz			
		1Hz	100.000kHz-999.999kHz				
		10Hz	1.0000	1.00000MHz-2.00000MHz			
Test Level	Voltage Range	5mVrms-1Vrms	5mVrms-1Vrms				
	Accuracy	± (10% x Setting Value+	± (10% x Setting Value+2mV)				
	Resolution	1mVrms	5mVrms-1Vrms				
		10mVrms	1Vrms-	1Vrms-2Vrms			
V_{GS}	Range	0 - ±40V					
	Accuracy	1% x Setting Voltage+8r	1% x Setting Voltage+8mV				
	Resolution	1mV	0V - ±	10V			
V_{DS}	Range	0 - ±200V		0 - ±1500V	0 - ±3000V		
	Accuracy	1%×Setting Voltage + 1	1%×Setting Voltage + 100mV				
Output Impedance		100Ω,±2%@1kHz	100Ω, ±2%@1kHz				
Computation		Absolute deviation ∆ from	Absolute deviation Δ from nominal value, percent deviation from nominal value $\Delta\%$				

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Used for Bin signal output		
Standard 9-pin, crossed		
Can receive modification or external RS232 to RS485 module		
60 Minutes		
100-120VAC/198-242VAC Option, 47-63Hz		
More than 130VA		
430x177x405		
16kg		
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